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RELIABILITY REPORT  
FOR

DS2174, Rev A1

Dallas Semiconductor

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**Conclusion:**

The following qualification successfully meets the quality and reliability standards required of all Dallas Semiconductor products and processes:

DS2174, Rev A1

In addition, Dallas Semiconductor's continuous reliability monitor program ensures that all outgoing product will continue to meet Maxim's quality and reliability standards. The current status of the reliability monitor program can be viewed at <http://www.maxim-ic.com/TechSupport/dsreliability.html>.

**Device Description:**

A description of this device can be found in the product data sheet. You can find the product data sheet at [http://dbserv.maxim-ic.com/l\\_datasheet3.cfm](http://dbserv.maxim-ic.com/l_datasheet3.cfm).

**Reliability Derating:**

The Arrhenius model will be used to determine the acceleration factor for failure mechanisms that are temperature accelerated.

$$AfT = \exp((Ea/k) * (1/Tu - 1/Ts)) = tu/ts$$

AfT = Acceleration factor due to Temperature  
tu = Time at use temperature (e.g. 55°C)  
ts = Time at stress temperature (e.g. 125°C)  
k = Boltzmann's Constant (8.617 x 10<sup>-5</sup> eV/°K)  
Tu = Temperature at Use (°K)  
Ts = Temperature at Stress (°K)  
Ea = Activation Energy (e.g. 0.7 ev)

The activation energy of the failure mechanism is derived from either internal studies or industry accepted standards, or activation energy of 0.7ev will be used whenever actual failure mechanisms or their activation energies are unknown. All deratings will be done from the stress ambient temperature to the use ambient temperature.

An exponential model will be used to determine the acceleration factor for failure mechanisms, which are voltage accelerated.

$$AfV = \exp(B * (Vs - Vu))$$

AfV = Acceleration factor due to Voltage  
Vs = Stress Voltage (e.g. 7.0 volts)  
Vu = Maximum Operating Voltage (e.g. 5.5 volts)  
B = Constant related to failure mechanism type (e.g. 1.0, 2.4, 2.7, etc.)

The Constant, B, related to the failure mechanism is derived from either internal studies or industry accepted standards, or a B of 1.0 will be used whenever actual failure mechanisms or their B are unknown. All deratings will be done from the stress voltage to the maximum operating voltage. Failure rate data from the operating life test is reported using a Chi-Squared statistical model at the 60% or 90% confidence level (Cf).

The failure rate, Fr, is related to the acceleration during life test by:

$$Fr = X / (ts * AfV * AfT * N * 2)$$

X = Chi-Sq statistical upper limit  
N = Life test sample size

Failure Rates are reported in FITs (Failures in Time) or MTTF (Mean Time To Failure). The FIT rate is related to MTTF by:

$$MTTF = 1/Fr$$

NOTE: MTTF is frequently used interchangeably with MTBF.

The calculated failure rate for this device/process is:

**FAILURE RATE:**                      **MTTF (YRS): 9400**                      **FITS: 12.1**

The parameters used to calculate this failure rate are as follows:

**Cf: 60%**                      **Ea: 0.7**                      **B: 0**                      **Tu: 25 °C**                      **Vu: 5.5 Volts**

The reliability data follows. At the start of this data is the device information. This is a description of the device either used as a reliability test vehicle for a process / assembly qualification / monitor or a device used as part of a product qualification / monitor. Following this is the assembly information. This section includes a description of the assembly vehicle used to generate this reliability data for both qualifications and monitors. The next section is the detailed reliability data for each stress found in the qualification / monitor. If there are additional processes or assemblies used as part of this report, a description of each will follow which includes the respective reliability data for that process/ assembly. The reliability data section includes the latest data available.

**Device Information:**

Device: DS2174  
 Process: 1P, 4M,0.35um, Sil.P1, Ti/TiN M1-M4 ,BPSG,Masked N+ES  
 Passivation: Passivation w/Nov TEOS Oxide-Nitride  
 Die Size: 131 x 134  
 Number of Transistors: 300000  
 Interconnect: Aluminum / 1% Silicon / 0.5% Copper  
 Gate Oxide Thickness: 120 Å

**Assembly Information:**

Qualification Vehicle: DS2174  
 Assembly Site: ATP (Amkor, PI)  
 Pin Count: 44  
 Package Type: PLCC  
 Body Size: 650x650x3.87  
 Mold Compound: Nitto MP8000C  
 Lead Frame: Stamped Copper CDA151  
 Lead Finsh: SnPb Plate  
 Die Attach: 8361J Epoxy Silverfilled Ablebond  
 Bond Wire / Size: Au / 1.0 mil  
 Flammability: UL 94-V0  
 Moisture Sensitivity (JEDEC J-STD20A) Level 3  
 Date Code Range: 0152 to 0152

**ELECTRICAL CHARACTERIZATION**

DESCRIPTION	DATE CODE	CONDITION	READPOINT	QUANTITY	FAILS
ESD SENSITIVITY	0152	EOS/ESD S5.1 HBM 500 VOLTS	2 PULSES	3	0

ESD SENSITIVITY	0152	EOS/ESD S5.1 HBM 1000 VOLTS	2	PULSES	3	0
ESD SENSITIVITY	0152	EOS/ESD S5.1 HBM 1500 VOLTS	2	PULSES	3	0
ESD SENSITIVITY	0152	EOS/ESD S5.1 HBM 2000 VOLTS	2	PULSES	3	3
ESD SENSITIVITY	0152	EOS/ESD S5.1 HBM 4000 VOLTS	2	PULSES	3	3
LATCH-UP	0152	JESD78, I-TEST 125C			3	0
LATCH-UP	0152	JESD78, Vsupply TEST 125C			3	0
ESD SENSITIVITY	0152	EOS/ESD S5.1 HBM 500 VOLTS	1	PULSES	3	0
ESD SENSITIVITY	0152	EOS/ESD S5.1 HBM 1000 VOLTS	1	PULSES	3	0
ESD SENSITIVITY	0152	EOS/ESD S5.1 HBM 2000 VOLTS	1	PULSES	3	2
ESD SENSITIVITY	0152	EOS/ESD S5.1 HBM 4000 VOLTS	1	PULSES	3	3
ESD SENSITIVITY	0152	EOS/ESD S5.1 HBM 8000 VOLTS	1	PULSES	3	3
LATCH-UP	0152	JESD78, I-TEST 125C			3	0
LATCH-UP	0152	JESD78, Vsupply TEST 125C			3	0
					<b>Total:</b>	<b>14</b>

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#### HIGH TEMPERATURE OPERATING LIFE

DESCRIPTION	DATE CODE	CONDITION	READPOINT	QUANTITY	FAILS	
HIGH VOLTAGE LIFE	0152	125C, 3.5 VOLTS	1000 HOURS	80	0	
					<b>Total:</b>	<b>0</b>

**FAILURE RATE:                    MTTF (YRS): 9400                    FITS: 12.1**